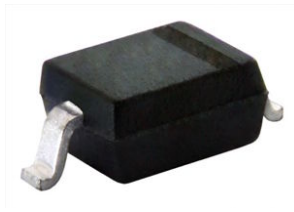




# Small Signal Fast Switching Diode



### FEATURES

- Silicon epitaxial planar diode
- Fast switching diodes
- AEC-Q101 qualified
- Base P/N-E3 - RoHS-compliant, commercial grade
- Base P/N-HE3 - RoHS-compliant, AEC-Q101 qualified
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



RoHS COMPLIANT

### MECHANICAL DATA

Case: SOD-323

Weight: approx. 4.3 mg

Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box

08/3K per 7" reel (8 mm tape), 15K/box

| PARTS TABLE |                                    |                       |              |               |
|-------------|------------------------------------|-----------------------|--------------|---------------|
| PART        | ORDERING CODE                      | INTERNAL CONSTRUCTION | TYPE MARKING | REMARKS       |
| 1N4448WS    | 1N4448WS-E3-08 or 1N4448WS-E3-18   | Single diode          | A3           | Tape and reel |
|             | 1N4448WS-HE3-08 or 1N4448WS-HE3-18 |                       |              |               |

| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)      |                                    |                    |       |      |
|--|------------------------------------|--------------------|-------|------|
| PARAMETER  | TEST CONDITION                     | SYMBOL             | VALUE | UNIT |
| Reverse voltage  |                                    | V <sub>R</sub>     | 75    | V    |
| Repetitive peak reverse voltage  |                                    | V <sub>RRM</sub>   | 100   | V    |
| Average rectified current half wave rectification with resistive load <sup>(1)</sup> | f ≥ 50 Hz                          | I <sub>F(AV)</sub> | 150   | mA   |
| Surge forward current  | t < 1 s and T <sub>j</sub> = 25 °C | I <sub>FSM</sub>   | 350   | mA   |
| Power dissipation <sup>(1)</sup>   |                                    | P <sub>tot</sub>   | 200   | mW   |

| THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                |                   |               |      |
|--|----------------|-------------------|---------------|------|
| PARAMETER  | TEST CONDITION | SYMBOL            | VALUE         | UNIT |
| Thermal resistance junction to ambient air <sup>(1)</sup>                      |                | R <sub>thJA</sub> | 650           | K/W  |
| Junction temperature   |                | T <sub>j</sub>    | 150           | °C   |
| Storage temperature range  |                | T <sub>stg</sub>  | - 65 to + 150 | °C   |
| Operating temperature range  |                | T <sub>op</sub>   | - 55 to + 150 | °C   |

### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature.



| ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |  |          |       |      |       |               |
|---|--|----------|-------|------|-------|---------------|
| PARAMETER   | TEST CONDITION   | SYMBOL   | MIN.  | TYP. | MAX.  | UNIT          |
| Forward voltage   | $I_F = 5\text{ mA}$  | $V_F$    | 0.620 |      | 0.720 | V             |
|   | $I_F = 100\text{ mA}$  | $V_F$    |       |      | 1     | V             |
| Leakage current   | $V_R = 20\text{ V}$  | $I_R$    |       |      | 25    | nA            |
|   | $V_R = 75\text{ V}$  | $I_R$    |       |      | 5     | $\mu\text{A}$ |
|   | $V_R = 20\text{ V}, T_j = 150\text{ }^{\circ}\text{C}$                             | $I_R$    |       |      | 50    | $\mu\text{A}$ |
| Diode capacitance   | $V_F = V_R = 0\text{ V}$   | $C_D$    |       |      | 4     | pF            |
| Reverse recovery time   | $I_F = 10\text{ mA}, I_R = 1\text{ mA}, V_R = 6\text{ V}, R_L = 100\text{ }\Omega$ | $t_{rr}$ |       |      | 4     | ns            |

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

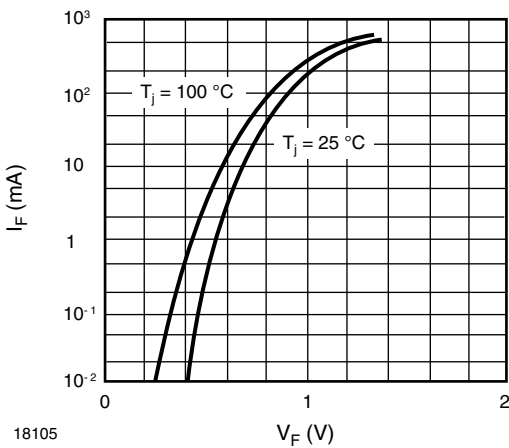


Fig. 1 - Forward Characteristics

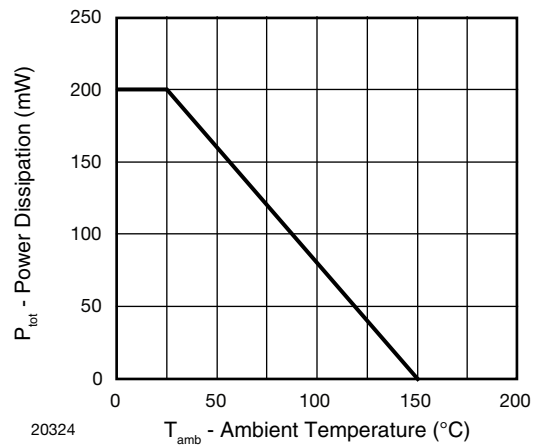


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

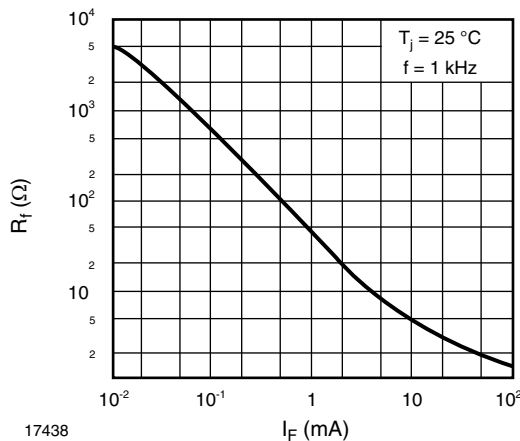


Fig. 2 - Dynamic Forward Resistance vs. Forward Current

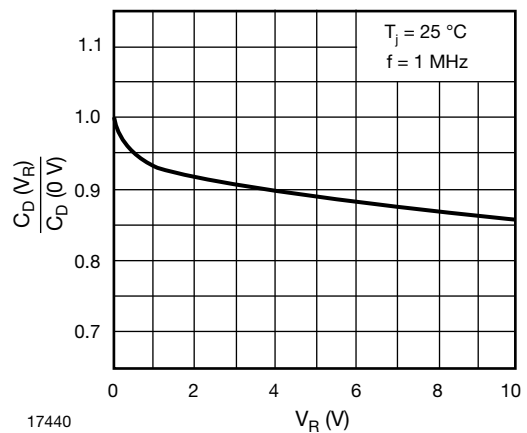


Fig. 4 - Relative Capacitance vs. Reverse Voltage

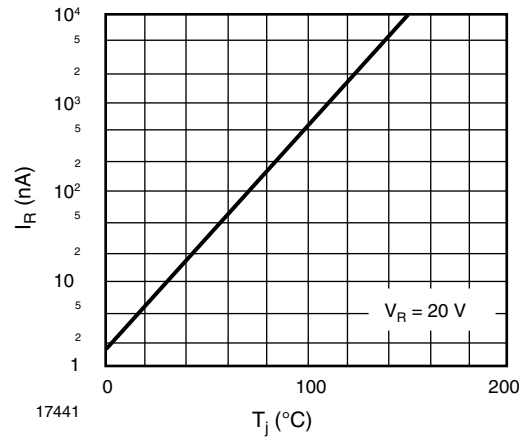


Fig. 5 - Leakage Current vs. Junction Temperature

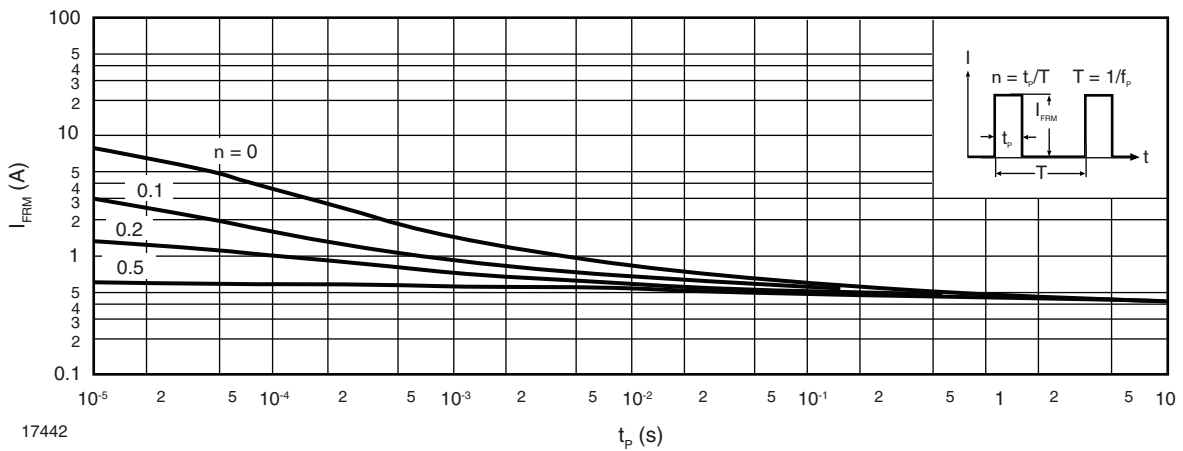
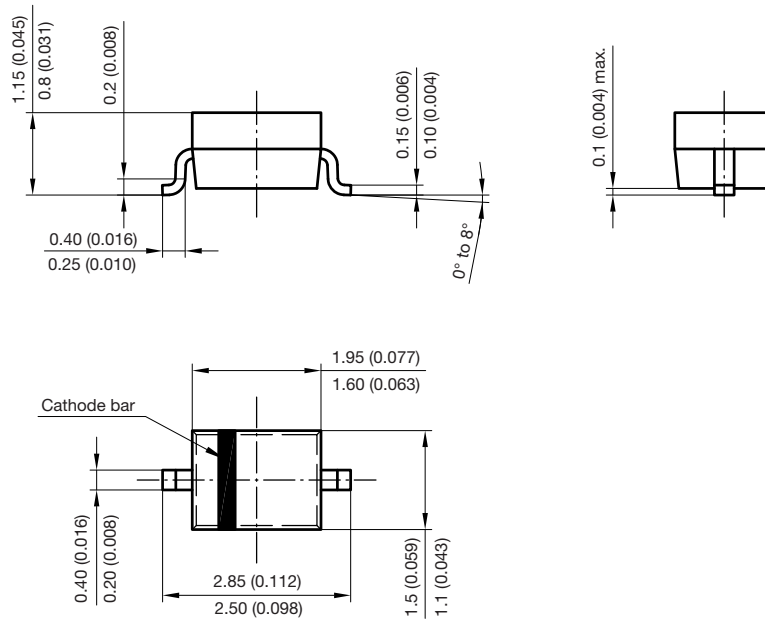


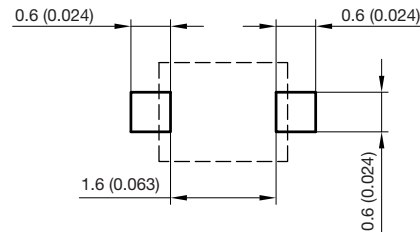
Fig. 6 - Admissible Repetitive Peak Forward Current vs. Pulse Duration



PACKAGE DIMENSIONS in millimeters (inches): SOD-323



Foot print recommendation:



Document no.:S8-V-3910.02-001 (4)  
 Created - Date: 24.August.2004  
 Rev. 5 - Date: 23.Sept.2009  
 17443



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